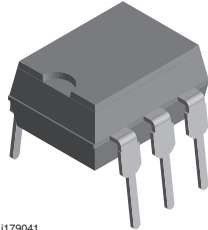
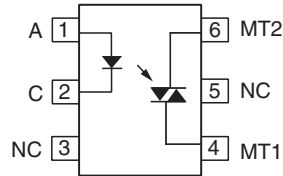


## Optocoupler, Phototriac Output, High dV/dt, Very Low Input Current



I179041



### DESCRIPTION

The IL4216/IL4217/IL4218 consists of an AlGaAs IRLED optically coupled to a pair of photosensitive non-zero crossing SCR chips and are connected inversely parallel to form a TRIAC. These three semiconductors are assembled in a six pin 0.3 inch dual in-line package.

High input sensitivity is achieved by using an emitter follower phototransistor and a cascaded SCR predriver resulting in an LED trigger current of less than 1.3 mA (DC).

The IL4216/IL4217/IL4218 uses two discrete SCRs resulting in a commutating dV/dt of greater than 10 kV/μs. The use of a proprietary dV/dt clamp results in a static dV/dt of greater than 10 kV/μs. This clamp circuit has a MOSFET that is enhanced when high dV/dt spikes occur between MT1 and MT2 of the TRIAC. The FET clamps the base of the phototransistor when conducting, disabling the internal SCR predriver.

The blocking voltage of up to 800 V permits control of off-line voltages up to 240 VAC, with a safety factor more than two, and is sufficient for as much as 380 VAC. Current handling capability is up to 300 mA RMS, continuous at 25 °C.

The IL4216/IL4217/IL4218 isolates low-voltage logic from 120, 240, and 380 VAC lines to control resistive inductive, or capacitive loads including motors solenoids, high current thyristors or TRIAC and relays.

### FEATURES

- High input sensitivity  $I_{FT} = 1.3 \text{ mA}$
- 300 mA on-state current
- High static dV/dt 10000 V/μs, typical
- Inverse parallel SCRs provide commutating dV/dt > 10 kV/μs
- Very Low Leakage < 10 μA
- Isolation test voltage 5300 V<sub>RMS</sub>
- Lead (Pb)-free component
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC


**RoHS**  
COMPLIANT

### APPLICATIONS

- Solid state relay
- Industrial controls
- Office equipment
- Consumer appliances

### AGENCY APPROVALS

- UL1577, file no. E52744 system code J
- CSA 93751
- DIN EN 60747-5-2 (VDE 0884)/DIN EN 60747-5-5 pending available with option 1
- BSI IEC 60950; IEC 60065
- FIMKO

### ORDER INFORMATION

PART	REMARKS
IL4216	600 V V <sub>DRM</sub> , DIP-6
IL4217	700 V V <sub>DRM</sub> , DIP-6
IL4218	800 V V <sub>DRM</sub> , DIP-6
IL4216-X006	600 V V <sub>DRM</sub> , DIP-6 400 mil (option 6)
IL4216-X009	600 V V <sub>DRM</sub> , SMD-6 (option 9)
IL4217-X007	700 V V <sub>DRM</sub> , SMD-6 (option 7)
IL4217-X009	700 V V <sub>DRM</sub> , SMD-6 (option 9)
IL4218-X006	800 V V <sub>DRM</sub> , DIP-6 400 mil (option 6)
IL4218-X007	800 V V <sub>DRM</sub> , SMD-6 (option 7)
IL4218-X009	800 V V <sub>DRM</sub> , SMD-6 (option 9)

#### Note

For additional information on the available options refer to option information.

ABSOLUTE MAXIMUM RATINGS (1)					
PARAMETER	TEST CONDITION	PART	SYMBOL	VALUE	UNIT
<b>INPUT</b>					
Reverse voltage			$V_R$	6.0	V
Forward current			$I_F$	60	mA
Surge current			$I_{FSM}$	2.5	A
Power dissipation			$P_{diss}$	100	mW
Derate linearly from 25 °C				1.33	mW/°C
Thermal resistance			$R_{th}$	750	°C/W
<b>OUTPUT</b>					
Peak off-state voltage		IL4216	$V_{DRM}$	600	V
		IL4217	$V_{DRM}$	700	V
		IL4218	$V_{DRM}$	800	V
RMS on-state current			$I_{DRM}$	300	mA
Single cycle surge			$I_{TSM}$	3.0	A
Power dissipation			$P_{diss}$	300	mW
Derate linearly from 25 °C				6.6	mW/°C
Thermal resistance			$R_{th}$	150	°C/W
<b>COUPLER</b>					
Creepage distance				≥ 7.0	mm
Clearance				≥ 7.0	mm
Storage temperature			$T_{stg}$	- 55 to + 150	°C
Ambient temperature			$T_{amb}$	- 55 to + 100	°C
Isolation test voltage			$V_{ISO}$	5300	$V_{RMS}$
Isolation resistance	$V_{IO} = 500\text{ V}, T_{amb} = 25\text{ °C}$		$R_{IO}$	≥ $10^{12}$	$\Omega$
	$V_{IO} = 500\text{ V}, T_{amb} = 100\text{ °C}$		$R_{IO}$	≥ $10^{11}$	$\Omega$
Lead soldering temperature (2)	5.0 s		$T_{slid}$	260	°C

### Notes

(1)  $T_{amb} = 25\text{ °C}$ , unless otherwise specified.

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability.

(2) Refer to reflow profile for soldering conditions for surface mounted devices (SMD). Refer to wave profile for soldering conditions for through hole devices (DIP).



ELECTRICAL CHARACTERISTICS							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
<b>INPUT</b>							
Forward voltage	$I_F = 20 \text{ mA}$		$V_F$		1.3	1.5	V
Breakdown voltage	$I_R = 10 \text{ }\mu\text{A}$		$V_{BR}$	6.0	30		V
Reverse current	$V_R = 6.0 \text{ V}$		$I_R$		0.1	10	$\mu\text{A}$
Input capacitance	$V_F = 0 \text{ V}, f = 1.0 \text{ MHz}$		$C_{IN}$		40		pF
Thermal resistance, junction to lead			$R_{thjl}$		750		$^{\circ}\text{C/W}$
<b>OUTPUT</b>							
Repetitive peak off-state voltage	$I_{DRM} = 100 \text{ }\mu\text{A}$	IL4216	$V_{DRM}$	600	650		V
		IL4217	$V_{DRM}$	700	750		V
		IL4218	$V_{DRM}$	800	850		V
Off-state voltage	$I_{D(RMS)} = 70 \text{ }\mu\text{A}$	IL4216	$V_{D(RMS)}$	424	460		V
		IL4217	$V_{D(RMS)}$	484	536		V
		IL4218	$V_{D(RMS)}$	565	613		V
Off-state current	$V_D = 600 \text{ V}, T_{amb} = 100 \text{ }^{\circ}\text{C}$		$I_{D(RMS)}$		10	100	$\mu\text{A}$
Reverse current	$V_R = 600 \text{ V}, T_{amb} = 25 \text{ }^{\circ}\text{C}$		$I_{RMS}$		10	100	$\mu\text{A}$
On-state voltage	$I_T = 300 \text{ mA}$		$V_{TM}$		1.7	3.0	V
On-state current	$PF = 1.0, V_{T(RMS)} = 1.7 \text{ V}$		$I_{TM}$			300	mA
Surge (non-repetitive, on-state current)	$f = 50 \text{ Hz}$		$I_{TSM}$			3.0	A
Holding current	$V_T = 3.0 \text{ V}$		$I_H$		65	200	$\mu\text{A}$
Latching current	$V_T = 2.2 \text{ V}$		$I_L$		5.0		mA
LED trigger current	$V_{AK} = 5.0 \text{ V}$		$I_{FT}$		0.7	1.3	mA
Critical rate of rise of off-state voltage	$V_D = 0.67 V_{DRM}, T_{amb} = 25 \text{ }^{\circ}\text{C}$		$dV/dt_{cr}$	10000			V/ $\mu\text{s}$
	$V_D = 0.67 V_{DRM}, T_{amb} = 80 \text{ }^{\circ}\text{C}$		$dV/dt_{cr}$	5000			V/ $\mu\text{s}$
Critical rate of rise of voltage at current commutation	$V_D = 0.67 V_{DRM},$ $dI/dt_{crq} \leq 15 \text{ A/ms},$ $T_{amb} = 25 \text{ }^{\circ}\text{C}$		$dV/dt_{crq}$	10000			V/ $\mu\text{s}$
	$V_D = 0.67 V_{DRM},$ $dI/dt_{crq} \leq 15 \text{ A/ms},$ $T_{amb} = 80 \text{ }^{\circ}\text{C}$		$dV/dt_{crq}$	5000			V/ $\mu\text{s}$
Off-state current	$I_T = 300 \text{ mA}$		$dI/dt$		100		A/ms
Thermal resistance, junction to lead			$R_{thjl}$		150		$^{\circ}\text{C/W}$
<b>COUPLER</b>							
Capacitance (input to output)	$f = 1.0 \text{ MHz}, V_{IO} = 0 \text{ V}$		$C_{IO}$		0.8		pF
Critical rate of rise of coupled input to output voltage	$I_T = 0, V_{RM} = V_{DM} = 300 \text{ VAC}$		$dV_{(IO)}/dt$	5000	1.0		mA

**Note**

$T_{amb} = 25 \text{ }^{\circ}\text{C}$ , unless otherwise specified.

Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.

## POWER FACTOR CONSIDERATIONS

A snubber is not needed to eliminate false operation of the TRIAC driver because of the IL4216/IL4217/IL4218 high static and commutating dV/dt with loads between 1 and 0.8 power factors. When inductive loads with power factors less than 0.8 are being driven, include a RC snubber or a single capacitor directly across the device to damp the peak commutating dV/dt spike. Normally a commutating dV/dt causes a turning-off device to stay on due to the stored energy remaining in the turning-off device.

But in the case of a zero voltage crossing optotriac, the commutating dV/dt spikes can inhibit one half of the TRIAC from turning on. If the spike potential exceeds the inhibit voltage of the zero cross detection circuit, half of the TRIAC will be held-off and not turn-on. This hold-off condition can be eliminated by using a snubber or capacitor placed directly across the optotriac as shown in Figure 1. Note that the value of the capacitor increases as a function of the load current.

The hold-off condition also can be eliminated by providing a higher level of LED drive current. The higher LED drive provides a larger photocurrent which causes the phototransistor to turn-on before the commutating spike has activated the zero cross network. Figure 8 shows the relationship of the LED drive for power factors of less than 1.0. The curve shows that if a device requires 1.5 mA for a resistive load, then 1.8 times (2.7 mA) that amount would be required to control an inductive load whose power factor is less than 0.3.

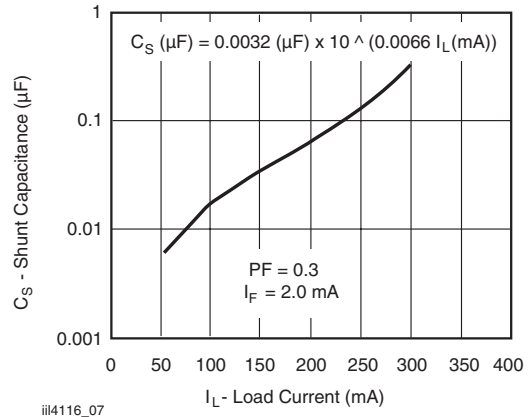


Fig. 3 - Shunt Capacitance vs. Load Current vs. Power Factor

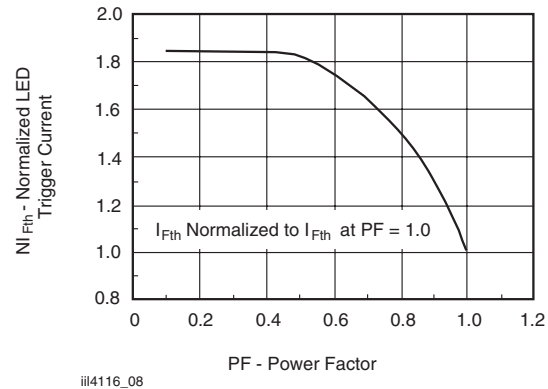


Fig. 4 - Normalized LED Trigger Current

## TYPICAL CHARACTERISTICS

T<sub>amb</sub> = 25 °C, unless otherwise specified

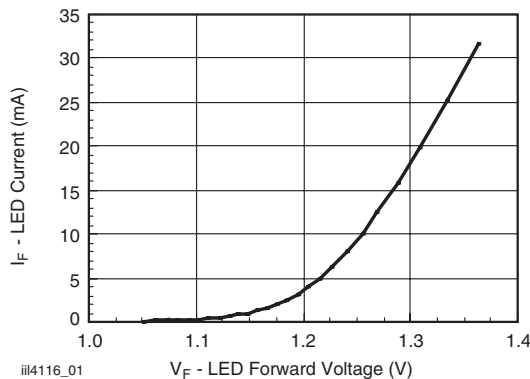


Fig. 5 - LED Forward Current vs. Forward Voltage

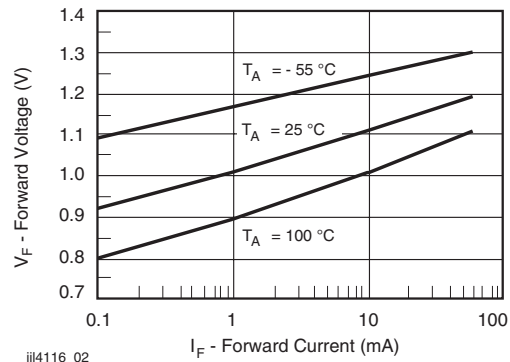
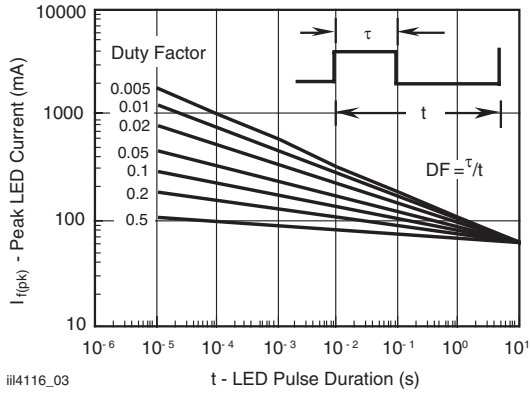
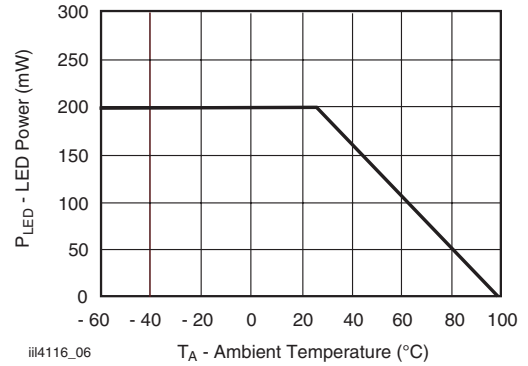


Fig. 6 - Forward Voltage vs. Forward Current



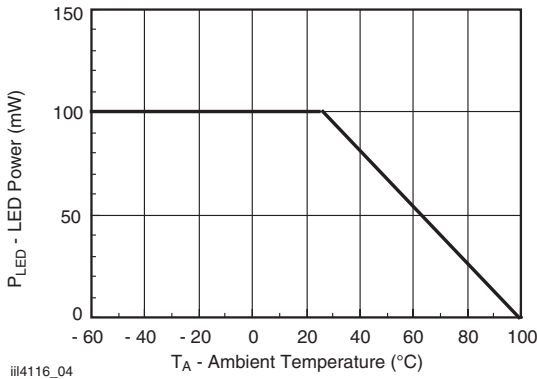
iii4116\_03

Fig. 7 - Peak LED Current vs. Duty Factor,  $\tau$



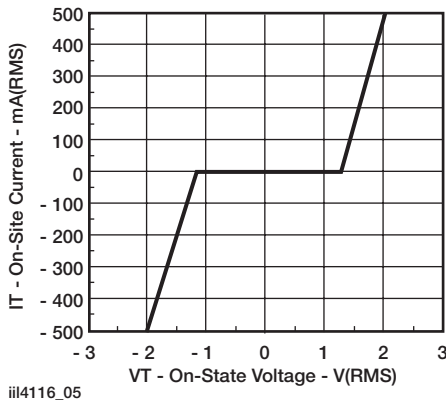
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Fig. 10 - Maximum Output Power Dissipation



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Fig. 8 - Maximum LED Power Dissipation



iii4116\_05

Fig. 9 - On-State Terminal Voltage vs. Terminal Current

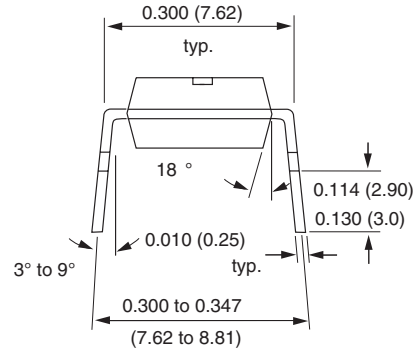
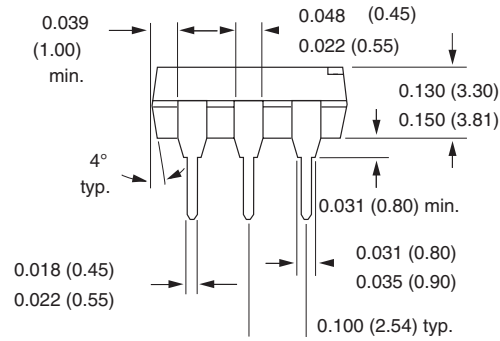
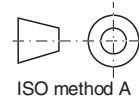
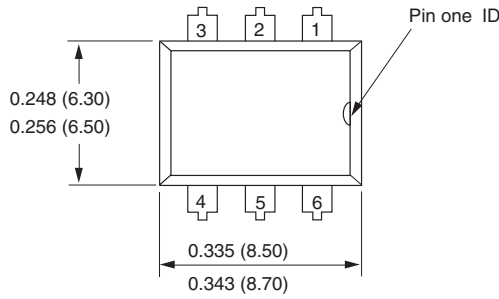
# IL4216/IL4217/IL4218



Vishay Semiconductors

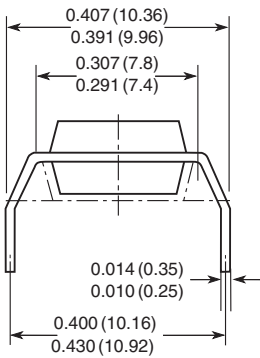
Optocoupler, Phototriac Output,  
High dV/dt, Very Low Input Current

## PACKAGE DIMENSIONS in inches (millimeters)

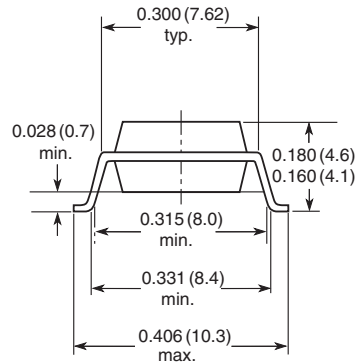


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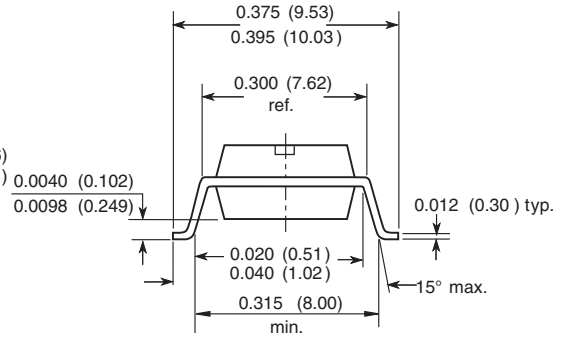
### Option 6



### Option 7



### Option 9



18450

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1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

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2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA.
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

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